

LF13006/LF13007 Digital Gain Set

General Description

The LF13006 and LF13007 are precision digital gain sets used for accurately setting non-inverting op amp gains. Gains are set with a 3-bit digital word which can be latched in with $\overline{\rm WR}$ and $\overline{\rm CS}$ pins. All digital inputs are TTL and CMOS compatible.

The LF13006 shown below will set binary scaled gains of 1, 2, 4, 8, 16, 32, 64, and 128. The LF13007 will set gains of 1, 2, 5, 10, 20, 50, and 100 (a common attenuator sequence). In addition, both versions have several taps and two uncommitted matching resistors that allow customization of the gain.

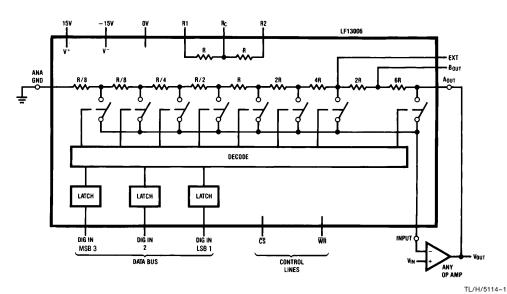
The gains are set with precision thin film resistors. The low temperature coefficient of the thin film resistors and their excellent tracking result in gain ratios which are virtually independent of temperature.

The LF13006, LF13007 used in conjunction with an amplifier not only satisfies the need for a digitally programmable amplifier in microprocessor based systems, but is also useful for discrete applications, eliminating the need to find 0.5% resistors in the ratio of 100 to 1 which track each other over temperature.

Features

- TTL and CMOS compatible logic levels
- Microprocessor compatible
- Gain error 0.5% max
- Binary or scope knob gains
- \blacksquare Wide supply range + 5V to \pm 18V
- Packaged in 16-pin DIP

Block Diagram and Typical Application (LF13006)



Note: R \simeq 15 k Ω

Order Number LF13006N or LF13007N See NS Package Number N16A

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Operating Ratings (Note 1)

Operating Temperature Range -40°C to $+85^{\circ}\text{C}$ Lead Temp. (Soldering, 10 seconds) 260°C

Electrical Characteristics (Note 2)

Parameter	Conditions	Typ (Note 3)	Tested Limit (Note 4)	Design Limit (Note 5)	Units
Gain Error	$A_{OUT} = \pm 10V$ ANA GND = 0V $I_{INPUT} < 10 nA$	0.3	0.5	0.5	%(max)
Gain Temperature Coefficient	$A_{OUT} = \pm 10V$ ANA GND = 0V	0.001			%/°C
Digital Input Voltage Low High		1.4 1.6	0.8 2.0	0.8 2.0	V(max) V(min)
Digital Input Current Low High	V _{IL} = 0V V _{IH} = 5V	-38 0.0001	-100 1	- 100 1	μΑ(max) μΑ(max)
Positive Power Supply Current	All Logic Inputs Low	2	5	5	mA(max)
Negative Power Supply Current	All Logic Inputs Low	-1.7	-5	-5	mA(max)
Write Pulse Width, tW	$V_{IL}=0V, V_{IH}=5V$		150		ns(min)
Chip Select Set-Up Time, t _{CS}	$V_{IL}=0V, V_{IH}=5V$		250		ns(min)
Chip Select Hold Time, t _{CH}	$V_{IL}=0V, V_{IH}=5V$		0		ns(min)
DIG IN Set-Up Time, t _{DS}	V _{IL} =0V, V _{IH} =5V		150		ns(min)
DIG IN Hold Time, t _{DH}	V _{IL} =0V, V _{IH} =5V		60		ns(min)
Switching Time for Gain Change	(Note 4)	200			ns(max)
Switch On Resistance		3			kΩ
Unit Resistance, R		15	12-18		kΩ
R1 and R2 Mismatch		0.3	0.5	0.5	%(max)
R1/R2 Temperature Coefficient		0.001			%/°C

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its specified operating conditions.

Note 2: Parameters are specified at $V^+ = 15V$ and $V^- = -15V$. Min V^+ to ground voltage is 5V. Min V^+ to V^- voltage is 5V. Boldface numbers apply over full operating temperature ranges. All other numbers apply at $T_A = T_1 = 25^{\circ}C$.

Note 3: Typicals are at 25°C and represent most likely parametric norm.

Note 4: Guaranteed and 100% production tested.

Note 5: Guaranteed (but not 100% production tested) over the operating temperature. These limits are not used to calculate outgoing quality levels.

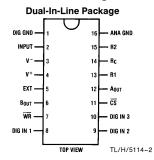
Note 6: Settling time for gain change is the switching time for gain change plus settling time (see section on Settling Time).

Note 7: $\overline{\text{WR}}$ minimum high threshold voltage increases to 2.4V under the extreme conditions when all three digital inputs are simultaneously taken from 0V to 5V at a slew rate of greater than 500V/ μ S.

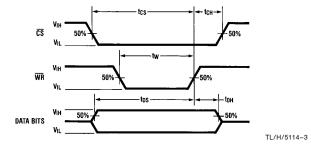
GAIN TABLE

Digital Input			Gain			
			LF13006		LF13007	
DIG in 3	DIG in 2	DIG in 1	A _{OUT}	B _{OUT}	A _{OUT}	B _{OUT}
0	0	0	1	1	1	1
0	0	1	2	1.25	1.25	1
0	1	0	4	2.5	2	1.6
0	1	1	8	5	5	4
1	0	0	16	10	10	8
1	0	1	32	20	20	16
1	1	0	64	40	50	40
1	1	1	128	80	100	80

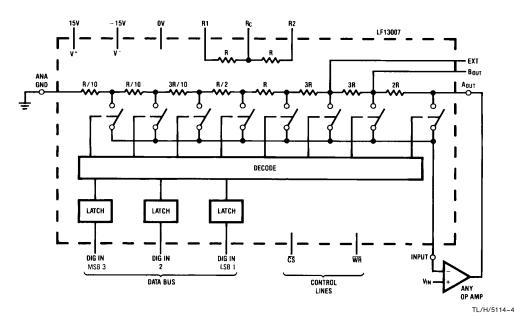
Connection Diagram



Switching Waveforms

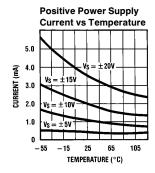


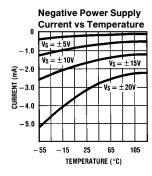
Block Diagram and Typical Application (Continued) (LF13007)

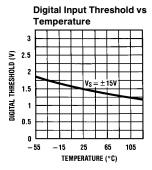


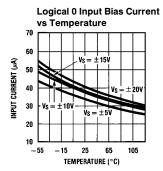
Note: R $\,\cong\,$ 15 k Ω

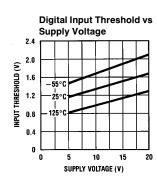
Typical Performance Characteristics

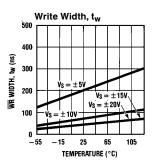


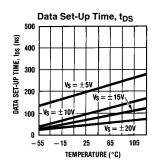


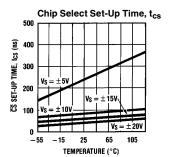












TL/H/5114-5

Application Information

FLOW-THROUGH OPERATION

THE LF13006, LF13007 can be operated with control lines $\overline{\text{CS}}$ and $\overline{\text{WR}}$ grounded. In this mode new data on the digital inputs will immediately set the new gain value. Input data cannot be latched in this mode.

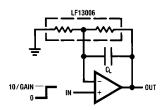
INPUT CURRENT

Current flowing through the input (pin 2) due to bias current of the op amp will result in a gain error due to switch impedance. Normally this error is very small. For example, 10 nA of bias current flowing through 3 k Ω of switch resistance will result in an error of 30 μV at the summing node. However, applications that have significant current flowing through the input must take this effect into account.

SETTLING TIME

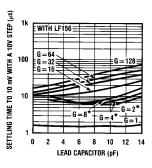
Settling time is a function of the particular op amp used with the LF13006/7 and the gain that is selected. It can be optimized and stability problems can be prevented through the use of a lead capacitor from the inverting input to the output of the amplifier. A lead capacitor is effective whenever the feedback around an amplifier is resistive, whether with discrete resistors or with the LF13006/7. It compensates for the feedback pole created by the parallel resistance and capacitance from the inverting input of the op amp to AC ground.

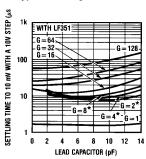
Settling Time Test Circuit

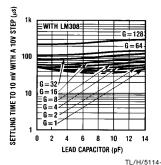


TL/H/5114-6

Typical Settling Time Curves



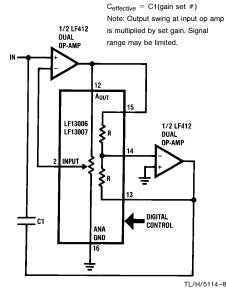




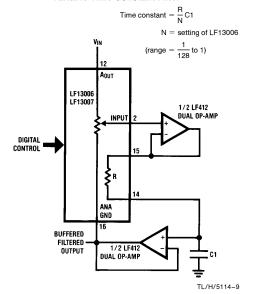
* Unstable at C_L less than 2 pF

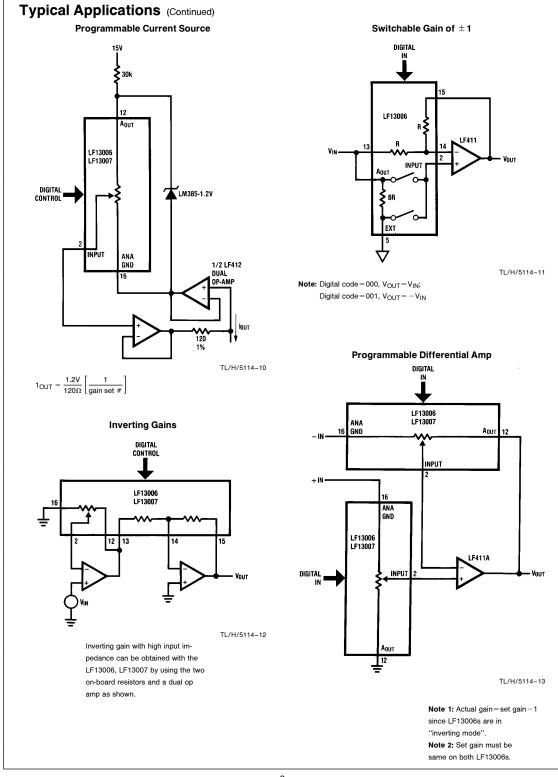
Typical Applications

Variable Capacitance Multiplier



Variable Time Constant Filter

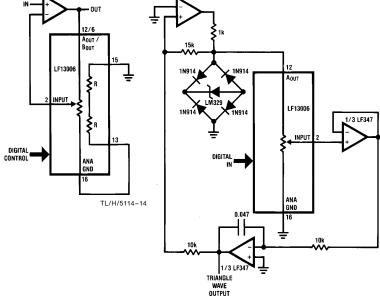


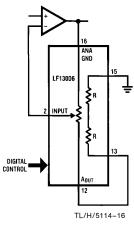




One Octave per Bit Function Generator

Variable Gains of Almost 1



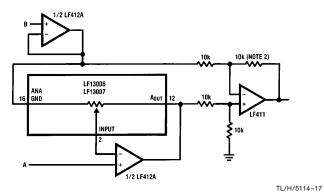


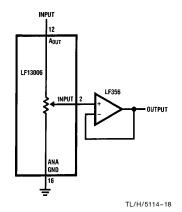
TL/H/5114-15

		TL/H/5114–15	
GAINS			GAINS
A _{OUT}	B _{OUT}		9
1	1		1.8
1.8	1.2		1.29
3	2		1.125
4.5	3		1.059
6	4		1.029
7.2	4.8		
8	5.33		1.014
8.47	5.65		1.007

Programmable Instrumentation Amp

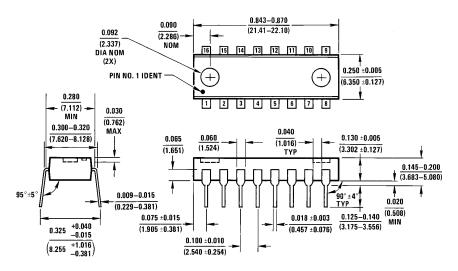
Attenuator (0 dB to -42 dB in 6 dB steps)





Note 1: $V_{OUT} = N$ (A-B), N = set gain. Note 2: All 10k resistors 0.1% matched.

Physical Dimensions inches (millimeters)



Molded Dual-In-Line Package (N)
Order Number LF13006N or LF13007N
NS Package Number N16A

N16A (REV E)

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